

Attorney Docket No. 0756-7272

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:)	Group Art Unit: 2811
Hongyong ZHANG et al.)	Examiner:
Serial No. 10/808,353)	CERTIFICATE OF MAILING I hereby certify that this correspondence is
Filed: March 25, 2004)	being deposited with the United States Posta Service with sufficient postage as First Class
For: SEMICONDUCTOR DEVICE AND)	Mail in an envelope addressed to Commissioner for Patents, P.O. Box 1450
METHOD FOR ITS PREPARATION)	Alexandria, VA 22313-1450, or 7-7-04

REQUEST FOR CORRECTED PTO 1449 FORM

Honorable Commissioner of Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

It has come to the attention of Applicant that the two of the articles listed on the PTO 1449 Form accompanying the Information Disclosure Statement filed March 25, 2004 need be revised to include further information. Specifically, Volume 60, No. 2, pages 225-227, should be added to the citation for the article entitled *In Situ Transmission Electron Microscopy Studies of Silicide-Mediated Crystallization of Amorphous Silicon*, and pages 8279-8289 should be added to the citation of the article entitled *Silicide Formation and Silicide-Mediated Crystallization of Nickel-Implanted Amorphous Silicon Thin Films*. Therefore, it is respectfully requested that the Examiner line through the erroneous listing on the PTO 1449 filed March 25, 2004, and evidence his consideration of the above-mentioned articles by initialing the attached PTO 1449 Form.

Respectfully submitted,

Eric J. Robinson Reg. No. 38;285 Robinson Intellectual Property Law Office, P.C. PMB 955 21010 Southbank Street Potomac Falls, Virginia 20165 (571) 434-6789

Approved for use through 10/31/2002. OMB 0651-0031

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Substitute for form 1449A/PTO				Complete if Known		
APPRORMATION DISCLOSURE				Application Number	10/808,353	
-	• *		Filing Date	March 25, 2004		
STATEMENT BY APPLICANT (use as many sheets as necessary)		First Named Inventor	Hongyong ZHANG, et al.			
		Group Art Unit	2811			
				Examiner Name		
Sheet	1	of	4	Attorney Docket Number	0756-7272	

U.S. PATENT DOCUMENTS							
	Cite No.	U.S. Pate	ent Document	Name of Patentee or Applicant of Cited	Date of Publication of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
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Examiner Initials*	Cite No. ¹				or (in CAPITAL LETTERS), urnal, serial, symposium, catal publisher, city and/or count	og, etc.)., date, page(s), volum		T ²	
			C. Hayzelden et al., "In Situ Transmission Electron Microscopy Studies of Silicide- Mediated Crystallization of Amorphous Silicon," Volume 60, No. 2, Pages 225-227.						
		Hayzelden et al., "Silicide Formation and Silicide-Mediated Crystallization of Nickel- Implanted Amorphous Silicon Thin Films," J. Appl. Phys., Vol. 73, No. 12, 15 June 1993, Pages 8279-8289.							

Examiner	Date	
Signature	Considered	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Burden Hour Statement: This form is estimated to take 2.0 hours to complete. Time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, Washington, DC 20231. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, Washington, DC 20231.

¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

¹ Unique citation designation number. ² Applicant is to place a check mark here if English language Translation is attached.